Document Number: 94411

Revision: 11-Aug-08

ST380CHPbF Series

Vishay High Power Products

Phase Control Thyristors (Hockey PUK Version), 960 A

FEATURES

- · Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- · Extended temperature range
- · Low profile hockey PUK to increase current-carrying capability
- · Lead (Pb)-free
- · Designed and qualified for industrial level

TYPICAL APPLICATIONS

- · DC motor controls
- · Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
1			A						
I _{T(AV)}	T _{hs}	80	°C						
		2220	A						
I _{T(RMS)}	T _{hs}	25	°C						
	50 Hz	12 500							
I _{TSM}	60 Hz	13 000	A						
l ² t	50 Hz	782	kA ² s						
1-1	60 Hz	713	KA-S						
V _{DRM} /V _{RRM}		400 to 600	V						
t _q	Typical	100	μs						
TJ		- 40 to 150	°C						

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS										
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA						
ST380CHC	04	400	500	100						
01000010	06	600	700	100						







TO-200AB (E-PUK)

960 A

PRODUCT SUMMARY

I_{T(AV)}



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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL		TEST CON	DITIONS	VALUES	UNITS		
Maximum average on-state current	1	180° condu	ction, half sine v	960 (440)	А			
at heatsink temperature	I _{T(AV)}	double side	(single side) co	oled	80 (110)	°C		
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	heatsink tempe	erature double side cooled	2220			
		t = 10 ms	No voltage		12 500			
Maximum peak, one-cycle		t = 8.3 ms	reapplied		13 000	A		
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		10 500			
		t = 8.3 ms	reapplied	Sinusoidal half wave,	11 000			
		t = 10 ms	No voltage reapplied	initial $T_J = T_J$ maximum	782	kA ² s		
Marine 12t fac finaina	l ² t	t = 8.3 ms			713			
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		553			
		t = 8.3 ms	reapplied		505			
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10) ms, no voltage	reapplied	7820	kA²√s		
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$(I_{T(AV)}), T_J = T_J maximum$	0.85	v		
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi x I_{T(AV)}), T_J = T_J maximum$					
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), T _J = T _J maximum		0.25	mΩ			
High level value of on-state slope resistance	r _{t2}	$(I > \pi x I_{T(AV)}), T_J = T_J maximum$		0.24	11122			
Maximum on-state voltage	V _{TM}	$I_{pk} = 2900 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.58	V			
Maximum holding current	Ι _Η	T _ 05 °C	anada aupply 1	2 V resistive load	600	mA		
Typical latching current	١ _L	$i_{\rm J} = 25^{-1} {\rm C},$	anoue supply 1		1000			

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega, t_r \leq$ 1 μs T_J = T_J maximum, anode voltage \leq 80 % V_{DRM}	1000	A/µs
Typical delay time	t _d	Gate current 1 A, dl _g /dt = 1 A/ μ s V _d = 0.67 % V _{DRM} , T _J = 25 °C	1.0	
Typical turn-off time	tq	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/µs, V _R = 50 V, dV/dt = 20 V/µs, gate 0 V 100 Ω, t _p = 500 µs	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	100	mA

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TRIGGERING						
PARAMETER	SYMBOL	TE	VAL			
PARAMETER	STINDUL		ST CONDITIONS	TYP.	MAX.	
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	w
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	vv
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 ms$	3	.0	А
Maximum peak positive gate voltage	+ V _{GM}		t < 5 mc	20		v
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms		5.0		
		T _J = - 40 °C		200	-	
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Maximum required gate trigger/	100	200	mA
		T _J = 150 °C	current/voltage are the lowest	40	-	
		$T_J = -40 \ ^\circ C$	value which will trigger all units	2.5	-	
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V
		T _J = 150 °C		1.0	-	
DC gate current not to trigger	I _{GD}		Maximum gate current/voltage not to trigger is the maximum	10		mA
DC gate voltage not to trigger	V _{GD}	$T_J = T_J maximum$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		v

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum operating junction temperature range	TJ		40 to 150	°C			
Maximum storage temperature range	T _{Stg}		- 40 to 150	°C			
Maximum thermal registeries, junction to besteink	D	DC operation single side cooled	0.09				
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.04	к/w			
Movimum thermal registeres, each to besteink	Р	DC operation single side cooled	0.02				
Maximum thermal resistance, case to heatsink	R _{thC-hs}	DC operation double side cooled	0.01				
Mounting force, ± 10 %			9800 (1000)	N (kg)			
Approximate weight			83	g			
Case style		See dimensions - link at the end of datasheet	TO-200AB (I	E-PUK)			

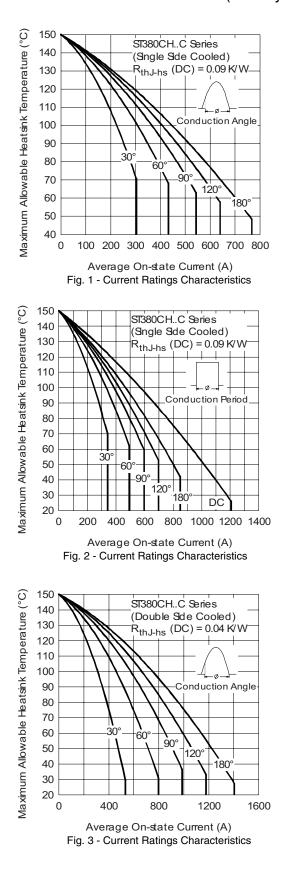
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION				TEST CONDITIONS	UNITS			
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE DOUBLE SIDE		TEST CONDITIONS	UNITS			
180°	0.010	0.011	0.007	0.007					
120°	0.012	0.012	0.012	0.013					
90°	0.015	0.015	0.016	0.017	$T_J = T_J$ maximum	K/W			
60°	0.022	0.022	0.023	0.023					
30°	0.036	0.036	0.036	0.037					

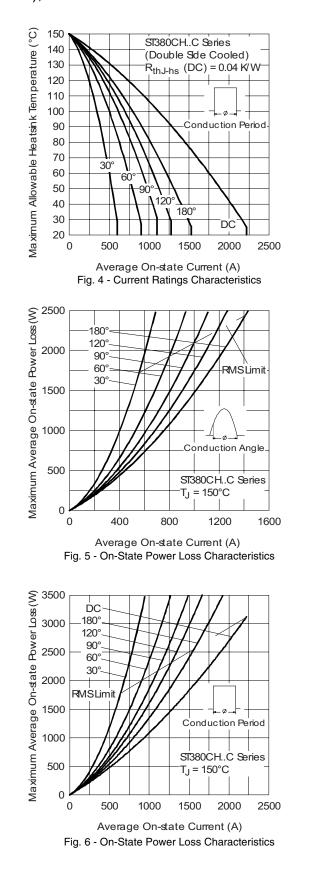
Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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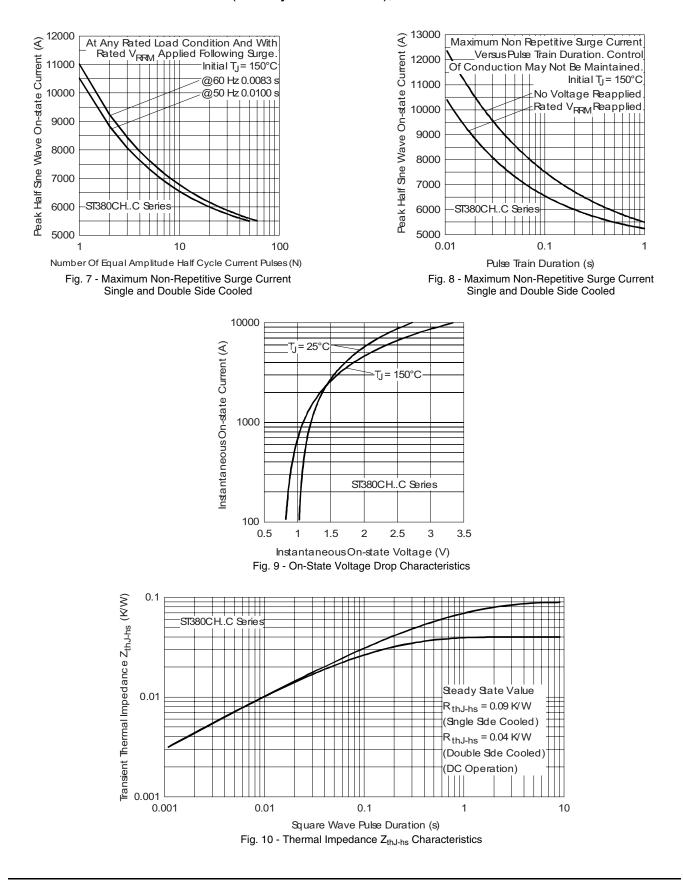






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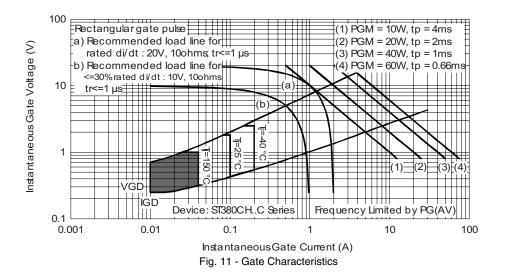


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ORDERING INFORMATION TABLE

Device code	ST	38	0	СН	06	С	1	-	PbF	
	1	2	3	4	5	6	7	8	9	
	1 -	- Thy	ristor							
	2 -		-	art numl ter grad						
	4 -			nic PUK		emperat	ture			
	5 - 6 -			de x 100 ase TO-2				Ratings	table)	
	7 -	0 =	Eyelet t	erminal	s (gate a	and aux	iliary ca		Insoldered l	
							-		unsoldered oldered lead	
			-				-		soldered lea	
	8 -	· Crit	ical dV/	dt: • No		0 V/µs (//µs (sp				
	9 -	Lea	ad (Pb)-f		- 1000 V	nha (sh				

LINKS TO RELATED DOCUMENTS					
Dimensions	http://www.vishay.com/doc?95075				
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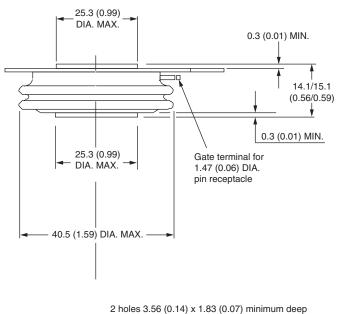


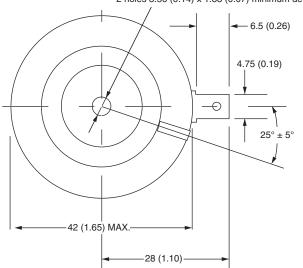
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TO-200AB (E-PUK)

DIMENSIONS in millimeters (inches)

Anode to gate Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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